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IN THE CLAIMS:

Please amend the claims as follows:

- 1. (Currently Amended) A light emitting display device comprising:
- a gate electrode provided formed over a substrate having an insulating surface with a substance having a photocatalytic function therebetween;
 - a gate insulating layer formed over the gate electrode;
- a semiconductor layer and a first electrode formed over the gate insulating layer;
 - a wiring layer formed over the semiconductor layer;
- a partition wall covering an edge portion of the first electrode and the wiring layer;
- an electroluminescent layer over the first electrode; and
 a second electrode over the electroluminescent layer, wherein the
 wiring layer covers the edge portion of the first electrode.
 - 2. (Original) A light emitting display device comprising:
- a wiring layer and a first electrode formed over a substrate having an insulating surface with a substance having a photocatalytic function therebetween;
 - a semiconductor layer formed over the wiring layer;
 - a gate insulating layer formed over the semiconductor layer;
 - a gate electrode formed over the gate insulating layer;
- a partition wall covering an edge portion of the first electrode and the wiring layer;
 - an electroluminescent layer over the first electrode; and
 - a second electrode over the electroluminescent layer,
- wherein the wiring layer covers the edge portion of the first electrode.

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3. (Original) A light emitting display device comprising:

a gate electrode formed over a substrate having an insulating surface with a substance having a photocatalytic function therebetween;

a gate insulating layer formed over the gate electrode;

a semiconductor layer and a first electrode formed over the gate insulating layer;

a wiring layer formed over the semiconductor layer;

a partition wall covering an edge portion of the first electrode and the wiring layer;

an electroluminescent layer over the first electrode; and a second electrode over the electroluminescent layer,

wherein the first electrode covers an edge portion of the wiring layer.

4. (Original) A light emitting display device comprising:

a wiring layer and a first electrode formed over a substrate having an insulating surface with a substance having a photocatalytic function therebetween:

a semiconductor layer formed over the wiring layer;

a gate insulating layer formed over the semiconductor layer;

a gate electrode formed over the gate insulating layer;

a partition wall covering an edge portion of the first electrode and the wiring layer;

an electroluminescent layer over the first electrode; and

a second electrode over the electroluminescent layer,

wherein the first electrode covers an edge portion of the wiring layer.

5. (Original) A light emitting display device according to any one of claims 1 to 4, wherein the substance having a photocatalytic function comprises titanium oxide.

6. (Original) Alight emitting display device comprising:

a conductive layer including a refractory metal over a substrate having an insulating surface;

- a gate electrode formed over the conductive layer;
- a gate insulating layer formed over the gate electrode;
- a semiconductor layer and a first electrode formed over the gate insulating layer;
 - a wiring layer formed over the semiconductor layer;
- a partition wall covering an edge portion of the first electrode and the wiring layer;
 - an electroluminescent layer over the first electrode; and
- a second electrode over the electroluminescent layer, wherein the wiring layer covers the edge portion of the first electrode.

7. (Original) A light emitting display device comprising:

- a conductive layer including a refractory metal over a substrate having an insulating surface;
- a wiring layer and a first electrode formed over the conductive layer;
 - a semiconductor layer formed over the wiring layer;
- a gate insulating layer formed over the semiconductor layer; a gate electrode formed over the gate insulating layer;
- a partition wall covering an edge portion of the first electrode and the wiring layer;
 - an electroluminescent layer over the first electrode; and
- a second electrode over the electroluminescent layer, wherein the wiring layer covers the edge portion of the first electrode.

8. (Original) A light emitting display device comprising:

- a conductive layer including a refractory metal over a substrate having an insulating surface;
 - a gate electrode formed over the conductive layer;

a gate insulating layer formed over the gate electrode;

a semiconductor layer and a first electrode formed over the gate insulating layer;

a wiring layer formed over the semiconductor layer;

a partition wall covering an edge portion of the first electrode and the wiring layer;

an electroluminescent layer over the first electrode; and
a second electrode over the electroluminescent layer,
wherein the first electrode covers an edge portion of the wiring
layer.

9. (Original) A light emitting display device comprising:

a conductive layer including a refractory metal over a substrate having an insulating surface;

a wiring layer and a first electrode formed over the conductive layer;

a semiconductor layer formed over the wiring layer;

a gate insulating layer formed over the semiconductor layer;

a gate electrode formed over the gate insulating layer;

a partition wall covering an edge portion of the first electrode and the wiring layer;

an electroluminescent layer over the first electrode; and a second electrode over the electroluminescent layer, wherein the first electrode covers an edge portion of the wiring

10. (Original) A light emitting display device according to any one of claims 6 to 9, wherein the refractory metal is selected from the group consisting of Ti (titanium), W (tungsten), Cr (chromium), Al (aluminum), Ta (tantalum), Ni (nickel), Zr (zirconium), Hf (hafnium), V (vanadium), Ir (iridium), Nb (niobium), Pd (lead), Pt (platinum), Mo (molybdenum), Co (cobalt), and Rh (rhodium).

layer.

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11. (Original) A light emitting display device according to any one of claims 1-4 and 6-9, wherein the gate electrode and the wiring layer are made of a material selected from the group consisting of silver, gold, copper, and indium tin oxide.

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- 12. (Original) A light emitting display device according to any one of claims 1-4 and 6-9, wherein the semiconductor layer is a semi-amorphous semiconductor containing hydrogen and halogen and having a crystal structure.
- 13. (Original) A TV set including a display screen having the light emitting display device according to any one of claims 1-4 and 6-9.
- 14. (Original) A method for manufacturing a light emitting display device, comprising:

forming a gate electrode over a substrate having an insulating surface with a substance having a photocatalytic function therebetween by a droplet discharge method;

forming a gate insulating layer over the gate electrode;

forming a semiconductor layer over the gate insulating layer;

forming a first electrode over the gate insulating layer by a droplet discharge method;

forming a wiring layer over the semiconductor layer by a droplet discharge method to cover an edge of the first electrode;

forming a partition wall to cover the edge portion of the first electrode and the wiring layer;

forming an electroluminescent layer over the first electrode; and forming a second electrode over the electroluminescent layer by a droplet discharge method.

15. (Original) A method for manufacturing a light emitting display device, comprising:

forming a first electrode over a substrate having an insulating surface with a substance having a photocatalytic function therebetween by a droplet discharge method;

forming a wiring layer over the substrate having an insulating surface with a substance having a photocatalytic function therebetween to cover an edge portion of the first electrode;

forming a semiconductor layer over the wiring layer;

forming a gate insulating layer over the semiconductor layer;

forming a gate electrode over the gate insulating layer by a droplet discharge method;

forming a partition wall to cover the edge portion of the first electrode and the wiring layer;

forming an electroluminescent layer over the first electrode; and forming a second electrode over the electroluminescent layer by a droplet discharge method.

16. (Original) A method for manufacturing a light emitting display device, comprising:

forming a gate electrode over a substrate having an insulating surface with a substance having a photocatalytic function therebetween by a droplet discharge method;

forming a gate insulating layer over the gate electrode; forming a semiconductor layer over the gate insulating layer;

forming a wiring layer over the semiconductor layer by a droplet discharge method;

forming a first electrode over the gate insulating layer by a droplet discharge method to cover an edge portion of the wiring layer;

forming a partition wall to cover an edge portion of the first electrode and the wiring layer;

forming an electroluminescent layer over the first electrode; and forming a second electrode over the electroluminescent layer by a droplet discharge method.

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17. (Original) A method for manufacturing a light emitting display device, comprising:

forming a wiring layer over a substrate having an insulating surface with a substance having a photocatalytic function therebetween by a droplet discharge method;

forming a first electrode over the substrate having an insulating surface with a substance having a photocatalytic function therebetween by a droplet discharge method to cover an edge portion of the wiring layer;

forming a semiconductor layer over the wiring layer;

forming a gate insulating layer over the semiconductor layer;

forming a gate electrode over the gate insulating layer by a droplet discharge method;

forming a partition wall to cover an edge portion of the first electrode and the wiring layer;

forming an electroluminescent layer over the first electrode; and forming a second electrode over the electroluminescent layer by a droplet discharge method.

- 18. (Original) A method for manufacturing a light emitting display device according to any one of claims 14 to 17, wherein titanium oxide is used as the substance having a photocatalytic function.
- 19. (Original) A method for manufacturing a light emitting display device, comprising:

forming a conductive layer including a refractory metal over a substrate having an insulating surface;

forming a gate electrode over the conductive layer by a droplet discharge method;

forming a gate insulating layer over the gate electrode;

forming a semiconductor layer over the gate insulating layer;

forming a first electrode over the gate insulating layer by a droplet discharge method;

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forming a wiring layer over the semiconductor layer by a droplet discharge method to cover an edge portion of the first electrode;

forming a partition wall to cover the edge portion of the first electrode and the wiring layer;

forming an electroluminescent layer over the first electrode; and forming a second electrode over the electroluminescent layer by a droplet discharge method.

20. (Original) A method for manufacturing a light emitting display device, comprising:

forming a conductive layer including a refractory metal over a substrate having an insulating surface;

forming a first electrode over the conductive layer by a droplet discharge method;

forming a wiring layer over the conductive layer by a droplet discharge method to cover an edge portion of the first electrode;

forming a semiconductor layer over the wiring layer;

forming a gate insulating layer over the semiconductor layer;

forming a gate electrode over the gate insulating layer by a droplet discharge method;

forming a partition wall to cover the edge portion of the first electrode and the wiring layer;

forming an electroluminescent layer over the first electrode; and forming a second electrode over the electroluminescent layer by a droplet discharge method.

21. (Original) A method for manufacturing a light emitting display device, comprising:

forming a conductive layer including a refractory metal over a substrate having an insulating surface;

forming a gate electrode over the conductive layer by a droplet discharge method;

forming a gate insulating layer over the gate electrode;

forming a semiconductor layer over the gate insulating layer;

forming a wiring layer over the semiconductor layer by a droplet discharge method;

forming a first electrode over the gate insulating layer by a droplet discharge method to cover an edge portion of the wiring layer;

forming a partition wall to cover an edge portion of the first electrode and the wiring layer;

forming an electroluminescent layer over the first electrode; and forming a second electrode over the electroluminescent layer by a droplet discharge method.

22. (Original) A method for manufacturing a light emitting display device, comprising:

forming a conductive layer including a refractory metal over a substrate having an insulating surface;

forming a wiring layer over the conductive layer by a droplet discharge method;

forming a first electrode over the conductive layer by a droplet discharge method to cover an edge portion of the wiring layer;

forming a semiconductor layer over the wiring layer;

forming a gate insulating layer over the semiconductor layer;

forming a gate electrode over the gate insulating layer by a droplet discharge method;

forming a partition wall to cover an edge portion of the first electrode and the wiring layer;

forming an electroluminescent layer over the first electrode; and forming a second electrode over the electroluminescent layer by a droplet discharge method.

23. (Original) A method for manufacturing a light emitting display device according to any one of claims 19 to 22, wherein the refractory metal is selected

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from the group consisting of Ti (titanium), W (tungsten), Cr (chromium), Al (aluminum), Ta (tantalum), Ni (nickel), Zr (zirconium), Hf (hafnium), V (vanadium), Ir (iridium), Nb (niobium), Pd (lead), Pt (platinum), Mo (molybdenum), Co (cobalt), and Rh (rhodium).

- 24. (Currently Amended) A method for manufacturing a light emitting display device according to any one of claims 14 to 22 14-17, 19-21, and 22, wherein the gate electrode and the wiring layer are formed by using comprise a material selected from the group consisting of silver, gold, copper, and indium tin oxide.
- 25. (Currently Amended) A method for manufacturing a light emitting display device according to any one of claims 14 to 22 14-17, 19-21, and 22, wherein the semiconductor layer is formed by using comprises a semi-amorphous semiconductor containing hydrogen and halogen and having a crystal structure.